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Implementation of a Transmon Qubit Using Superconducting Granular Aluminum

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The high kinetic inductance offered by granular aluminum (grAl) has recently been employed for linear inductors in superconducting high-impedance qubits and kinetic inductance detectors. Because of its large critical current density compared to typical Josephson junctions, its resilience to external magnetic fields, and its low dissipation, grAl may also provide a robust source of nonlinearity for strongly driven quantum circuits, topological superconductivity, and hybrid systems. Having said that, can the grAl nonlinearity be sufficient to build a qubit? Here we show that a small grAl volume $(10 \times 200 \times 500 \text{ nm}^3)$ shunted by a thin film aluminum capacitor results in a microwave oscillator with anharmonicity α two orders of magnitude larger than its spectral linewidth Γ_{01} , effectively forming a transmon qubit. With increasing drive power, we observe several multiphoton transitions starting from the ground state, from which we extract $\alpha = 2\pi \times 4.48$ MHz. Resonance fluorescence measurements of the $|0\rangle \rightarrow |1\rangle$ transition yield an intrinsic qubit linewidth $\gamma = 2\pi \times 10$ kHz, corresponding to a lifetime of 16 μ s, as confirmed by pulsed time-domain measurements. This linewidth remains below $2\pi \times 150$ kHz for in-plane magnetic fields up to ~ 70 mT.

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I. INTRODUCTION

Superconducting circuits are part of a growing group of hardware platforms which successfully demonstrated quantum information processing, from quantum error correction to quantum limited amplification [1]. Some of the most promising platforms, such as spin qubits [2–4], topological materials [5–7], magnons [8], or molecular electronics [9–12], benefit from hybrid architectures where superconducting circuits can provide unique functionalities, in particular, dispersive readout [13] and high-impedance couplers. The success of superconducting circuits is linked to the availability of nonlinear elements with high intrinsic coherence, namely Josephson junctions (JJs) fabricated by thermal oxidation from thin film aluminum (Al) [14]. However, their applicability in hybrid systems [15,16] is Subject Areas: Condensed Matter Physics Quantum Information Superconductivity

limited by the low critical field of Al [17] and by the emergence of quantum interference effects in the JJs, even for magnetic fields aligned in plane [18]. Here we show that the JJ can be replaced by a small volume of granular aluminum (grAl) [19] providing enough nonlinearity to implement a superconducting transmon qubit [20], which we operate in magnetic fields up to ~ 0.1 T.

Granular aluminum, similarly to other materials such as NbN [21], NbTiN [22], or TiN [23], is an attractive choice for superconducting hybrid systems operating at radio frequencies, due to its large critical magnetic field [24,25], high coherence in the microwave domain [26–29], and intrinsic nonlinearity [30,31]. The constituent Al grains, about 3–5 nm in diameter [32], are separated by thin oxygen barriers; therefore, grAl structures can be modeled as arrays of JJs [30]. Their kinetic inductance is tunable over orders of magnitude up to nH/ \square [33].

Similar to JJ arrays, the nonlinearity of the grAl kinetic inductance stems from the Josephson coupling between neighboring grains, and it is inversely proportional to the critical current density j_c and the volume of the film V_{grAl} [30]. This nonlinearity gives rise to a frequency shift *K* of the fundamental plasmon mode ω_1 for each added photon

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 $(n \rightarrow n + 1)$. Although the values K(n) depend on the transition number n, to lowest order they can be approximated by a constant self-Kerr coefficient $K = C\pi ea(\omega_1^2/j_c V_{\text{grAl}})$, where C is a numerical factor close to unity that depends on the current distribution, e is the electron charge, and a is the grain size [30].

By reducing the grAl volume and the critical current density, one can potentially increase K(1) to a value much larger than the transition linewidth Γ_{01} , allowing one to map a qubit to the first two levels $|0\rangle$ and $|1\rangle$, similar to a transmon qubit [20]. Following this approach, we construct a circuit with a transition frequency $f_1 = 7.4887$ GHz by connecting an Al capacitor to a small volume of grAl, $V_{\text{grAI}} = 10 \times 200 \times 500 \text{ nm}^3$, with critical current density $j_c \approx 0.4 \text{ mA}/\mu\text{m}^2$ (see Fig. 1). For this structure the estimated anharmonicity $\alpha = K(1)$ is in the megahertz range [30]. Indeed, as we show below, the measured value is $\alpha = 2\pi \times 4.48$ MHz, which is much larger than the transition linewidth $\Gamma_{01} = 2\pi \times 50$ kHz, effectively implementing a relatively low anharmonicity transmon qubit.

II. QUBIT DESIGN AND DEVICE FABRICATION

Figure 1 shows a typical copper waveguide sample holder, together with the circuit design of our qubit, consisting of a grAl film shunted by an Al capacitor. From finite-element simulations we extract a shunt capacitance $C_s \approx 137$ fF and a geometric stray inductance $L_s \approx 0.45$ nH (cf. Appendix B). The outer electrode of the capacitor surrounds the inner electrode almost completely, except for a gap of width w [see Fig. 1(b)], which is used to tune the coupling rate κ between the qubit and the waveguide sample holder (cf. Appendix B).

The sample is fabricated on a sapphire wafer in a singlestep lithography by performing a three-angle shadow evaporation. First, a 10-nm-thick grAl layer with roomtemperature resistivity $\rho_n = 1800 \pm 200 \ \mu\Omega$ cm and corresponding critical temperature $T_c = 1.9$ K is deposited at zero angle, followed by two 40-nm-thick Al layers evaporated at $\pm 35^{\circ}$ (cf. Appendix J). Thanks to this procedure, only a small grAl volume, highlighted in blue in Fig. 1(d), remains unshunted by the pure Al layers and participates in the electromagnetic mode with a kinetic inductance $L_K = 2.85$ nH, constituting 86% of the total inductance.

III. RESONANCE FLUORESCENCE

A. Spectroscopy

We characterize the grAl transmon by performing a single-port measurement of the complex reflection coefficient S_{11} as a function of probe frequency f, in the vicinity of the resonant frequency f_1 (see Fig. 2). In the limit of weak driving, $\Omega_R \ll \alpha$, where Ω_R is the Rabi frequency, we can treat the transmon as a two-level system. If the decoherence rate is dominated by the energy relaxation rate Γ_{01} , similarly to Ref. [35] the complex reflection coefficient is



FIG. 1. Sample design. (a) Photograph of a copper waveguide sample holder equipped with a microwave port similar to Ref. [34], and, optionally, with a 2D vector magnet (see the Appendix A). The vector magnet is schematically represented by the blue and red coils, oriented along the y and z directions. The sample is positioned in the center of the waveguide and couples to its electric field along the y direction. (b) Optical image of the qubit sample, consisting of two Al pads forming a capacitor $C_s \approx 137$ fF, connected by a grAl inductor $L_k \approx 2.85$ nH. We adjust the coupling of the sample to the waveguide by changing the gap w (see Appendix B). (c),(d) Scanning electron microscope (SEM) image of the grAl inductor (false colored in blue) with volume $V_{\text{grAl}} = 10 \times 200 \times 500 \text{ nm}^3$ and the Al leads (false colored in red). The grainy surface structure is due to the antistatic Au layer used for imaging. The circuit is obtained in a single lithography step by performing a three-angle shadow evaporation. The Al layer shunts the grAl film in all areas, except for the volume $V_{\rm grAl}$ in the center, which constitutes the source of nonlinearity for the qubit [30]. The geometric inductance is $L_s = 0.45$ nH, and the contacts contribute to the L_k with 0.13 nH (see Appendix G).

$$S_{11}(\Delta) = 1 - \frac{2\kappa}{\Gamma_{01}} \frac{1 + i2\Delta/\Gamma_{01}}{1 + (2\Delta/\Gamma_{01})^2 + 2(\Omega_R/\Gamma_{01})^2}, \quad (1)$$

where $\Delta = \omega_1 - \omega$ is the frequency detuning between the drive and the qubit frequency and *i* is the unit imaginary number. In contrast to a harmonic oscillator, the reflection coefficient of a qubit deviates from a circle in the quadrature plane and becomes increasingly elliptic with drive power (cf. Appendix C).

Figure 2 depicts the measured reflection coefficient S_{11} as a function of qubit-drive detuning for incident on-chip powers $P_{\rm in}$ ranging between -168 and -138 dBm. From a least-squares fit to Eq. (1) (solid black lines), we extract the qubit frequency $f_1 = 7.4887$ GHz, as well as the internal loss and external coupling rates, $\gamma = 2\pi \times 10$ kHz and $\kappa = 2\pi \times 40$ kHz, respectively. The corresponding energy



FIG. 2. Resonance fluorescence. (a) Single-port reflection coefficient S_{11} measured around the qubit frequency $f_1 =$ 7.4887 GHz. For probe powers $P_{\rm in}$ well below the single-photon regime ($\bar{n} \ll 1$), S_{11} closely resembles a circle in the quadrature plane (dark blue markers), from which, using Eq. (1), we extract the external and internal decay rates $\kappa = 2\pi \times 40$ kHz and $\gamma = 2\pi \times 10$ kHz, respectively. In (b) and (c) we show the real and imaginary part of the reflection coefficient $\operatorname{Re}(S_{11})$ and $Im(S_{11})$, respectively, as a function of the detuning between the probe frequency f and the qubit frequency f_1 . When increasing the probe power $P_{\rm in}$, the response becomes elliptic in the quadrature plane, which is the signature of resonance fluorescence of a twolevel system [35]. The black lines indicate fits to the experimental data according to Eq. (1). The only fitting parameter is the Rabi frequency Ω_R ; κ and γ are fixed by the fit to the low power response [cf. panel (a)]. In (d) we show Ω_R^2 as a function of incident on-chip power P_{in} . For a two-level system, given by the limit $\Omega_R \ll \alpha$, we expect a linear dependence, as confirmed by the black dashed line passing through the coordinate origin.

relaxation times due to radiation into the waveguide [36] and internal losses are $T_{1,\kappa} \approx 4 \,\mu s$ and $T_{1,\gamma} \approx 16 \,\mu s$, respectively. As shown in Fig. 2(d), the Rabi frequency shows a linear dependence with drive amplitude, as expected for a two-level system. From a linear fit passing through the coordinate origin [35], we calibrate the attenuation of the input line to 103 dB, within 3 dB from room-temperature estimates.

For drive powers $P_{in} > -138$ dBm, we observe additional features in the reflection coefficient S_{11} emerging at frequencies f_n below the qubit frequency f_1 [see Fig. 3(a), left-hand panel]. Similar to the high power spectroscopy of JJ transmon qubits [37,38], these features are multiphoton transitions into higher energy eigenstates E_n starting from the ground state E_0 , observed at frequencies $f_n = (E_n - E_0)/(nh)$, where *n* is the level number (see Appendix D for numerical simulations of the spectrum and Appendix E for two-tone spectroscopy). From the frequency detuning between the first two transitions [red markers in Fig. 3(a), right-hand panel], we extract a qubit anharmonicity $\alpha = 2\pi \times 4.48$ MHz.

Generally, for a JJ transmon the anharmonicity is given by the charging energy $E_{c,s} = e^2/2C_s$ associated with the shunt capacitance [20], which for our geometry is $E_{c,s}/\hbar = 2\pi \times 141$ MHz. In the case of an array of N JJs, the anharmonicity is reduced by N^2 [39,40], which implies $N = \sqrt{E_{c,s}/\hbar \alpha} \approx 6$ for the JJ array implemented by our grAl volume [30]. The corresponding effective junctions are therefore separated by ~80 nm, spanning approximately ten grains. This result is in agreement with recent scanning tunneling microscopy measurements performed on similar grAl films, which evidenced the collective charging of clusters of grains [41].

From the measured multiphoton transition frequencies f_n , we calculate the nonlinear frequency shift $\hbar K(n) = (E_n - E_{n-1}) - (E_{n+1} - E_n)$, with $E_n/h = nf_n$. As shown in the right-hand panel of Fig. 3(a) (right-hand axis), we find that K(n) monotonically increases with n, likely due to the contribution of higher-order terms in the expansion of the Josephson potential, currently not included in the model [30].

In the top panel of Fig. 3(b) we show measurements for three different drive powers $P_{in} = -121$, -106, and -101 dBm. At any drive power in this range several multiphoton peaks are visible. The linewidth of each transition broadens with power, as illustrated in the bottom panel of Fig. 3(b) for the third and the tenth multiphoton transition. The visibility of the peaks and the background response of the phase is in remarkable agreement with the master-equation simulation presented in Appendix D. The broadening of the n = 10 transition, compared to n = 3, can be explained by offset charge dispersion, which increases with a power law in n [20].

B. Time domain

The time evolution of the qubit can also be measured using resonance fluorescence [42]. To enhance the signalto-noise ratio, we added a dimer Josephson junction array amplifier [43], operated in reflection, with a power gain $G_0 \gtrsim 20$ dB. In Fig. 4(a) we show the measured Rabi oscillations between the qubit's ground and first excited state, obtained by applying a Gaussian shaped manipulation pulse of duration τ_m . For the read-out, we demodulate the second half of a $3.2 - \mu$ s-long pulse with rectangular envelope and power $P_r \approx -152$ dBm. Both read-out and manipulation pulses are applied on resonance with the qubit transition frequency. As expected, the Rabi frequency increases linearly with the drive amplitude.

The energy relaxation time $T_1 = 1/\Gamma_{01}$, shown in the top panel of Fig. 4(b), is measured by preparing the qubit in the excited state using a 723-ns π pulse and monitoring the dependence of the qubit population inversion as a function



FIG. 3. Energy spectrum. (a) Phase of the measured reflection coefficient $\arg(S_{11})$ as a function of probe frequency f and incident onchip power P_{in} (left-hand panel). With increasing probe power we observe multiphoton transitions at frequencies f_n , labeled $(|0\rangle \rightarrow |n\rangle)/n$, where n denotes the level number, which are almost equidistant in frequency, as plotted in the right-hand panel. For clarity we only highlight with arrows the odd n transitions; all indices n are listed on the right-hand side of the 2D plot. From the first two points in the right-hand panel (highlighted in red) we extract the qubit anharmonicity $\alpha = K(1) = 2\pi \times 4.48$ MHz, much larger than the total linewidth $\kappa + \gamma = 2\pi \times 50$ kHz (see Fig. 2). To highlight the change in K(n) with increasing level number n (see main text), the red line shows a linear extrapolation from the first two points. The extracted values K(n) are plotted in orange using the right-hand axis. (b) Three individual measurements (top panel) performed at different probe powers ($P_{in} = -121, -106, \text{ and } -101 \text{ dBm}$), as indicated by the vertical dashed lines in the 2D plot in (a). Several multiphoton transitions are visible. With increasing power the linewidth of these transitions broadens, as shown in the bottom panels for n = 3 (right-hand panel, $P_{in} = -127$ to -123 dBm) and n = 10 (left-hand panel, $P_{in} = -105.75$ to -104.75 dBm). Here, $\delta_n = f - f_n$, with $f_3 = 7.4842$ GHz and $f_{10} = 7.4678$ GHz, as indicated by the arrows in the top panel. In Appendix D we show that these experimental results can be quantitatively reproduced by a master-equation simulation.



FIG. 4. Time-domain manipulation and measurements of the grAl transmon. (a) Rabi oscillations between the qubit's ground $|0\rangle$ and first excited state $|1\rangle$ as a function of the average drive power of the Gaussian shaped manipulation pulse P_m and its duration τ_m . The color scale represents the qubit population inversion from equilibrium (red) to fully inverted (blue). With increasing drive power, the Rabi frequency increases in agreement with the spectroscopy measurement (see Fig. 2 and Appendix C). The right-hand panel shows the Rabi oscillation for $P_m = -124.7$ dBm, highlighted in the 2D plot by a black arrow. The black dashed lines indicate an exponentially decaying envelope. (b) Measurement of the grAl transmon coherence times. The duration of the π pulse is 723 ns at a manipulation power $P_m = -131.4$ dBm. The markers in the top panel show the measured population inversion at a time τ after the π pulse, and the black line indicates an exponential fit with a characteristic energy relaxation time $T_1 = 2.8 \ \mu s$. The bottom panel shows the results of a Ramsey-fringes (circles) and a Hahn-echo (triangles) measurement. The observed frequency of the Ramsey fringes agrees within 5% with the frequency detuning $\Delta_m = 2\pi \times 300$ kHz of the π pulse. From the fits indicated by solid lines, we extract coherence times $T_2 = 4.7 \ \mu s$ and $T_2^{\text{echo}} = 5.1 \ \mu s$, as well as the corresponding pure dephasing times 28 and 46 \mus, respectively. (c) Time stability of the energy relaxation time (gray triangles) and the deviation Δ of the qubit transition frequency from its average (pink markers corresponding to the right-hand axis). The pink shaded area is the uncertainty for the qubit frequency measurement. The inverted black triangles show the intrinsic energy relaxation time $T_{1,\gamma} = T_1 T_{1,\kappa} / (T_{1,\kappa} - T_1)$, where $T_{1,\kappa} = 3.1 \ \mu s$ (dashed line) is the limit due to spontaneous emission into the waveguide. Notably, the T_1 and frequency stability data were taken in different coold

of the wait time τ . The results are averaged over 3×10^5 repetitions during the course of 8 min. The observed energy decay is fitted by a single exponential function with characteristic decay time $T_1 = 2.8 \ \mu$ s. The bottom panel of Fig. 4(b) shows Ramsey fringes and Hahn-echo coherence measurements, performed with the same π pulse, yielding $T_2 = 4.7 \ \mu$ s and $T_2^{\text{echo}} = 5.1 \ \mu$ s, respectively. The corresponding pure dephasing times are 28 and 46 μ s. These measurements reveal energy relaxation as the main decoherence mechanism, justifying the limit $T_2 \approx 2T_1$ used for the derivation of the reflection coefficient in Eq. (1).

In Fig. 2(c), we show the fluctuations of T_1 and the qubit frequency monitored over 15 h. Although spontaneous emission into the waveguide limits the energy relaxation time to $T_{1,\kappa} = 3.1 \ \mu$ s, we can infer the intrinsic energy relaxation $T_{1,\gamma}$ (inverted triangles) from the measured T_1 values using $T_{1,\gamma} = T_1 T_{1,\kappa} / (T_{1,\kappa} - T_1)$. The obtained average intrinsic energy relaxation time is $T_{1,\gamma} = 20^{+22}_{-6} \ \mu$ s, consistent with the γ^{-1} values extracted from spectroscopy (see Fig. 2). The pink markers indicate the detuning Δ of the qubit frequency from its average value. The observed total change is on the order of the intrinsic linewidth γ .

IV. MAGNETIC FIELD RESPONSE

By applying a magnetic field B_y , aligned in plane with the sample, we observe a continuous decrease of the qubit frequency $f_1(B_y)$, as plotted in Fig. 5(a). The measurements are performed in two separate cooldowns, with (filled crosses) and without (open pentagons) an outer superconducting Al shield. When employing the shield, the



FIG. 5. Magnetic field dependence. (a) Relative change in qubit frequency $\delta f_1 = f_1(B_y) - f_1$ as a function of the applied inplane magnetic field B_y (see Appendix F for field alignment). The experimental data were measured in two separate cooldowns: with (filled triangles) and without (open pentagons) an outer superconducting Al shield (see Appendix A). The field dependence can be fitted to a two-fluid model [44] (see Appendix G), indicated by the black dashed line, from which we extract the thin film Al critical flux density $B_{c,Al} = 150 \pm 5$ mT, in agreement with Ref. [17]. A more detailed analysis of the qubit transition frequency with much higher resolution is presented in Appendix H. (b) Internal quality factor Q_i for the shielded (filled triangles) and unshielded (open pentagons and triangles) case versus the in-plane magnetic field B_y .

maximal field is limited to ~70 mT, after which the shield becomes affected by the field coils, introducing distortions in the field alignment. Because of the large critical field of grAl (~4–5 T [24,25]), the change in frequency is primarily due to the lowering of the Al gap Δ_{Al} , which leads to an increase of the kinetic inductance of the Al wires connecting the electrodes, accounting for ~10% of the total inductance.

Figure 5(b) depicts the internal quality factor Q_i as a function of the in-plane magnetic field B_y measured with (filled triangles) and without (open pentagons and triangles) an outer Al shield. Compared to the data depicted in Fig. 2, we attribute the lower internal quality factor in these three cooldowns to the removal of the μ -metal shield, which likely results in an increase of the (stray) B_{z} field. In the current design the Al pads are the most field susceptible components, rendering the qubit frequency and internal quality factor particularly sensitive to out-of-plane magnetic fields (cf. Appendix F), as illustrated by the factor of 3 difference in Q_i values in the unshielded case for nominally identical setups. Finally, it is important to note that the absolute value of the nonlinear frequency shift K is not expected to change in magnetic field, because the ratio ω_1^2/j_c in the expression for K is independent of the grAl superconducting gap. Indeed, we measure a constant K up to $\sim 100 \text{ mT}$ (cf. Appendix G), confirming the grAl transmon's resilience to moderate magnetic fields.

V. CONCLUSION AND OUTLOOK

In summary, we have shown that using small volumes of grAl can provide enough nonlinearity to implement magnetic field resilient superconducting qubits. We have implemented a transmon qubit [20] with an anharmonicity $\alpha = 2\pi \times 4.48$ MHz, which, although smaller than the typical values for JJ-based transmons, is much larger than the qubit linewidth $\Gamma_{01} = 2\pi \times 50$ kHz. This enables time-domain manipulation and measurement of the qubit, from which we extracted an intrinsic $T_{1,\gamma} = 20^{+22}_{-6} \ \mu s$, and a pure dephasing time exceeding tens of microseconds. We observe multiphoton transitions to the 20th order, showcasing the robustness of the grAl transmon to external drives; a valuable asset for strongly driven quantum circuits [45], in particular in the context of bosonic codes for quantum information [46–48]. Measuring the same qubit with less shielding, in the presence of in-plane magnetic fields up to ~ 70 mT, the intrinsic linewidth remains below $\gamma = 2\pi \times 150$ kHz, limited by the pure Al capacitor pads.

Following this proof-of-principle demonstration, future developments will focus on replacing all pure Al components with more field resilient materials, such as low-resistivity grAl [33] or Nb compounds [21,22,49]. This will allow us to operate coherent superconducting qubits in magnetic fields beyond 1 T. In the current design, the Al pads play the role of phonon and quasiparticle traps

[33,50], enhancing the coherence. In future designs, in which Al is substituted by other superconductors with higher gap and critical field, quasiparticle poisoning could be mitigated by adding dedicated phonon traps disconnected from the qubit [51,52]. In order to avoid lowering T_1 by the Purcell effect, following the recent nonperturbative design reported in Ref. [53], a cross-Kerr interaction to an ancilla mode could be used for read-out. The limitations on qubit manipulation fidelity can be mitigated with derivative removal via adiabatic gate pulses [54] and by adapting the design to decrease the grAl volume and critical current density, thereby increasing the anharmonicity. Furthermore, larger values of anharmonicity might be achieved in fluxonium qubits [28,55].

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APPENDIX A: 2D VECTOR MAGNET

The waveguide sample holder can be equipped with a 2D vector magnet, which consists of a pair of Helmholtz (HH) coils and a solenoid for field alignment, denoted compensation coil in the following [see Fig. 6(a)]. The field direction of the HH coils is aligned within machining precision with the in-plane direction of the chip y. The compensation field is oriented perpendicular to it, in the z direction, out of plane with respect to the sample. All coils are winded with the same type of NbTi, multifilament superconducting wire with diameter $d = 140 \ \mu m$ (Supercon Inc., 54S43). The winding parameters—the number of layers n_L and the number of windings per layer n_w —and the physical dimensions of the coils—radius R, length l, and vertical distance Δy (in the case of the HH coils)—are summarized in Fig. 6(b).



FIG. 6. Photograph of the cryogenic setup used for the magnetic field measurements in Fig. 5. The copper waveguide sample holder equipped with the 2D vector magnet (highlighted in color) is mounted at the dilution stage of a tabletop Sionludi dilution refrigerator [57] (gray scale), with a base temperature $T_{\text{base}} \approx 20\text{--}30$ mK. The flat copper cylinder visible in the lower part of the image is the lid of the outer shield (not shown), which consists of successive copper (Cu) and aluminum (Al) cylinders, similar to Ref. [58]. The Cu shield was used in all measurements presented in Fig. 5, while the Al shield was only used during the "shielded" cooldown. The inset shows the top view of the copper waveguide sample holder including the 2D vector magnet (top) and the numerically calculated Helmholtz field (bottom) B_{y} for a bias current $I_{coil} = 1$ A as a function of lateral position x. The magnetic field of the two Helmholtz coils is aligned within machining precision with the in-plane direction y of the thin films. The B_7 coil is the compensation coil we use to align *in situ* the in-plane field. (b) Table summarizing the geometric parameters for the coils of the 2D vector magnet: number of winding layers n_L , number of windings per layer n_w , total number of windings N_w , inner coil radius R, coil length l, vertical distance between Helmholtz coils Δy , magnetic flux density in y and z direction per 1 A of bias current, b_y and b_z , respectively.

From both coil geometries, we calculate the relation between the applied bias current I_{coil} and the magnetic flux density \vec{B} at position \vec{r} using the Biot-Savart law. For simplicity, we approximate the coils with $n_L \times n_w$ single loops. The loop radius depends on the layer number, and the position along the coil's symmetry axis depends on the winding number, both gradually increasing by the wire diameter $d = 140 \ \mu m$. Following the approach of Caparelli and Tomasi [59], we approximate the magnetic field components $B_r(\vec{r})$, in radial direction (parallel to the loop plane *xz*), and $B_v(\vec{r})$ by truncating the sum after 20 terms.

Figure 6(a) (bottom right) depicts the numerically calculated magnetic flux density of the HH coils as a function of the lateral position x for a bias current $I_{coil} = 1$ A and y = 0 mm. The center of the waveguide is the origin for x and y, as indicated by the black dashed lines (top right-hand panel). Since the magnetic flux density B_y changes by only 3% in the region where the sample chip is mounted ($-5 \le x \le 5$ mm), we take the value $b_y = 80$ mT/A to convert the HH bias current I_{coil} into a magnetic flux density. For the compensation coil we find a conversion factor $b_z = 50$ mT/A.

APPENDIX B: FINITE-ELEMENT METHOD SIMULATIONS

The eigenfrequency and external coupling rate of the circuit to the waveguide sample holder is simulated with a commercial finite-element method simulator (high-frequency structure simulator). The inductive contribution of the granular aluminum (grAl) volume is modeled with a linear lumped-element inductor L_k . Capacitive contributions arising from the grAl microstructure are not considered. In order to extract the lumped-element shunt capacitance C_s and geometric stray inductance L_s of our circuit design, we sweep the inductance L_k while keeping the design geometry fixed [see Fig. 7(a)]. The dimensions of the circuit geometry are listed in Table I. The simulated eigenfrequencies are fitted to the lumped-element model,

TABLE I. Geometrical parameters of the sample [see Fig. 1(b)]: sample width *b*, sample height *h*, gap in outer electrode *w*, length of the bridge connecting the capacitor pads l_b , width of capacitor pads w_f , and gap between capacitor pads g_f .

b (μm)	$h \ (\mu m)$	w (µm)	l_b (μ m)	${\scriptstyle(\mu\mathrm{m})}^{w_{f}}$	$g_f \ (\mu { m m})$
1000	800	300	400	100	100

$$f_1(L_k) = \frac{1}{2\pi\sqrt{C_s(L_k + L_s)}},$$
 (B1)

yielding $C_s = 137$ fF and $L_s = 450$ pH [see Fig. 7(a)].

The external quality factor can be varied over 3 orders of magnitude by changing the gap w in the outer electrode [see Figs. 1(b) and 7(b)]. As shown in Fig. 7(c), we confirm that Q_c does not significantly change with the lateral position x, up to $x = \pm 8$ mm. The measured sample is shifted by x = 4 mm from the center.

APPENDIX C: RESONANCE FLUORESCENCE: REFLECTION COEFFICIENT

In the limit of weak driving $\Omega_R \ll \alpha$, we describe our transmon [20] as an effective two-level system [35]. Under this assumption, the reflection coefficient is

$$S_{11} = 1 - \sqrt{\kappa} \frac{\langle \sigma_{-} \rangle}{\alpha_{\rm in}},\tag{C1}$$

where κ is the single-photon coupling rate to the waveguide, $\langle \sigma_{-} \rangle$ is the expectation value of the lowering operator in the



FIG. 7. Finite-element method simulations of the linearized circuit. (a) Simulated transition frequency f_1 of the linearized circuit obtained using the eigenmode solver of a commercial finite-element method simulator (high-frequency structure simulator). For the simulation, the grAl volume is substituted with a lumped-element inductance L_k which we sweep from 2 to 10 nH in order to fit the shunt capacitance C_s and additional geometric inductance L_s of our design using Eq. (B1). We extract $C_s = 137$ fF and $L_s = 450$ pH. As indicated by the dotted cursors, the measured frequency $f_1 = 7.4887$ GHz corresponds to a value $L_k = 2.85$ nH. (b) Simulated external quality factor Q_c as a function of the gap w in the outer electrode for $L_k = 2.85$ nH. Similarly to the design of Ref. [60], by closing the gap we can vary the external quality factor by 3 orders of magnitude. For clarity [cf. panel (c)], the color of the markers is related to the value of w. The colored dashed lines indicate the design value for the experiment and the black marker indicates the measured external quality factor $Q_c = 1.9 \times 10^5$ (see Fig. 2). (c) Simulated external quality factor as a function of the lateral chip position x and gap width w. The value of x is measured from the center of the waveguide to the symmetry axis of the circuit. Because of the large aspect ratio of the waveguide's cross section (30 mm × 6 mm), the external quality factor varies by less than a factor of 2 along x.

two-dimensional qubit subspace $\{|0\rangle, |1\rangle\}$, and α_{in} is the expectation value of the annihilation operator of the incident bosonic single-mode field amplitude a_{in} [61]. Here, we assume a classical drive $a_{in} = \alpha_{in}e^{-i\omega t}$, which has in general a complex amplitude α_{in} .

The expectation value of the lowering operator is expressed using the Pauli operators σ_x and σ_y : $\langle \sigma_- \rangle = (\langle \sigma_x \rangle - i \langle \sigma_y \rangle)/2$. The steady-state expectation values (time $t \to \infty$) for the Pauli operators σ_x , σ_y , σ_z under a continuous drive with amplitude Ω_R and detuning $\Delta = \omega_q - \omega$, in the presence of qubit energy relaxation at rate Γ_{01} and qubit dephasing at rate $\Gamma_2 = \Gamma_{01}/2 + \Gamma_{\varphi}$ (Γ_{φ} is the pure dephasing rate), are the following [61]:

$$\langle \sigma_x(\Omega_R, \Delta) \rangle = \Gamma_{01} \Gamma_2 \Omega_R (\Gamma_{01}(\Gamma_2^2 + \Delta^2) + \Gamma_2 \Omega_R^2)^{-1}, \quad (C2)$$

$$\langle \sigma_y(\Omega_R, \Delta) \rangle = \Gamma_{01} \Delta \Omega_R (\Gamma_{01}(\Gamma_2^2 + \Delta^2) + \Gamma_2 \Omega_R^2)^{-1}, \quad (C3)$$

$$\langle \sigma_z(\Omega_R, \Delta) \rangle = -1 + \Gamma_2 \Omega_R^2 (\Gamma_{01}(\Gamma_2^2 + \Delta^2) + \Gamma_2 \Omega_R^2)^{-1}.$$
(C4)

Using Eqs. (C2) and (C3),

$$\langle \sigma_{-} \rangle = \frac{1}{2} \frac{\Gamma_{01} \Gamma_2 \Omega_R - i \Gamma_{01} \Delta \Omega_R}{\Gamma_{01} (\Gamma_2^2 + \Delta^2) + \Gamma_2 \Omega_R^2}.$$
 (C5)

Inserting Eq. (C5) into Eq. (C1), the reflection coefficient writes

$$S_{11}(\Delta) = 1 - \frac{\sqrt{\kappa}\Omega_R}{2\alpha_{\rm in}} \frac{\Gamma_{01}\Gamma_2 - i\Gamma_{01}\Delta}{\Gamma_{01}(\Gamma_2^2 + \Delta^2) + \Gamma_2\Omega_R}.$$
 (C6)

The relation between the Rabi frequency Ω_R and the drive amplitude α_{in} is

$$\Omega_R = 2\sqrt{\kappa} \langle a_{\rm in} \rangle = 2\sqrt{\kappa} \alpha_{\rm in}. \tag{C7}$$

Using Eq. (C7) and in the limit of negligible pure dephasing $\Gamma_{\varphi} \ll \Gamma_{01}$, Eq. (C6) simplifies to

$$S_{11}(\Delta) = 1 - \frac{2\kappa}{\Gamma_{01}} \frac{1 + i2\Delta/\Gamma_{01}}{1 + (2\Delta/\Gamma_{01})^2 + 2(\Omega_R/\Gamma_{01})^2}, \quad (C8)$$

which is Eq. (1) in the main text. The factor in front of the second term of Eq. (C8) is the coupling efficiency κ/Γ_{01} , with $\Gamma_{01} = \kappa + \gamma$. It is a measure of the relative size of the internal loss rate γ compared to the external coupling rate κ .

Figure 8 shows the Rabi frequency extracted from spectroscopy, similar to Fig. 2, and the time-domain measurements shown in Fig. 4(a). The measurements follow the dependence expected for a two-level system given by Eq. (C7).



FIG. 8. Rabi frequency $f_R = \Omega_R/(2\pi)$ from spectroscopy and time-domain measurements. The blue markers (labeled spec.) indicate the Rabi frequency extracted from fits to the frequency dependence of the reflection coefficient according to Eq. (C8), similar to Fig. 2, while the red markers indicate the values extracted from the time-domain (TD) measurements shown in Fig. 4(a). Both spectroscopy and time-domain datasets were taken in the same cooldown (run no. 7). The black solid line represents the expected Rabi frequency for an ideal qubit according to Eq. (C7), and using $P_{\rm in} = P_m = \hbar \omega_a |\alpha_{\rm in}|^2$.

APPENDIX D: NUMERICAL CALCULATION OF THE KERR HAMILTONIAN

Since our transmon qubit has a relatively small anharmonicty α (see Fig. 3 main text), we can simulate our circuit as an anharmonic oscillator with self-Kerr coefficient $K = 2\pi \times 4.5$ MHz. This model is further justified by the weak dependence of K on the level number n as measured in Fig. 3. The driven Kerr Hamiltonian expressed in the rotating frame of the coherent drive applied at frequency ω is

$$H_{\text{Kerr}}/\hbar = \Delta a^{\dagger}a - \frac{K}{2}a^{\dagger 2}a^2 - \frac{\Omega}{2}(a^{\dagger} + a). \quad (\text{D1})$$

Here, $\Delta = \omega_1 - \omega$ is the detuning between the fundamental transition frequency ω_1 and the drive tone, a^{\dagger} and a are the bosonic single-mode field amplitude creation and annihilation operators, respectively, and Ω is the drive amplitude. Notably, the drive amplitude Ω corresponds to the Rabi frequency Ω_R , only in the limits $K \gg \kappa$ and $\Omega \ll K$. Both criteria are met in our experiment.

In analogy to Eq. (C1) in the case of a two-level system, the reflection coefficient of an (anharmonic) oscillator is [62,63]

$$S_{11} = 1 - \sqrt{\kappa} \frac{\langle a \rangle}{\alpha_{\rm in}}.$$
 (D2)

We calculate the expectation values $\langle a \rangle$ as a function of detuning Δ and drive amplitude Ω by solving the corresponding master equation numerically using QuTiP: [64,65].



FIG. 9. Numerical simulations of resonance fluorescence. Complex reflection coefficient S_{11} (a), its real part (b), and imaginary part (c), numerically calculated for probe frequencies faround the resonance frequency $f_1 = 7.4887$ GHz of the Kerr Hamiltonian in Eq. (D1). For comparison, the input drive power P_{in} , the Kerr coefficient $K = 2\pi \times 4.5$ MHz, and the decay rates $\gamma = 2\pi \times 10$ kHz and $\kappa = 2\pi \times 40$ kHz are set to be the same as in the experiment. The black lines indicate least-squares fits using Eq. (1). The only fit parameter is the Rabi frequency Ω_R reported in (d). The linear dependence of the Rabi frequency with drive amplitude and the quantitative agreement with the measured data shown in Fig. 2(d) confirm the validity of the qubit limit and the value of the input line attenuation A = 103 dB.

The master equation in Lindblad form in the presence of energy relaxation at rate Γ_{01} is

$$\dot{\rho}_s = -\frac{i}{\hbar} [H_{\text{Kerr}}, \rho_s] + \Gamma_1 \mathcal{D}[a](\rho_s). \tag{D3}$$

Here, ρ_s is the system density matrix, H_{Kerr} is the driven Kerr Hamiltonian given in Eq. (D1), and $\mathcal{D}[a](\rho)$ is the Lindblad superoperator introducing single-photon dissipation:

$$\mathcal{D}[a](\rho_s) = a\rho_s a^{\dagger} - \frac{1}{2}a^{\dagger}a\rho_s - \frac{1}{2}\rho_s a^{\dagger}a.$$
 (D4)

For our numerical calculations, we use internal and external decay rates $\gamma = 2\pi \times 10 \text{ kHz}$ and $\kappa = 2\pi \times 40 \text{ kHz}$, respectively, and a total energy relaxation rate $\Gamma_{01} = \kappa + \gamma = 2\pi \times 50 \text{ kHz}$. The dimension of the considered Hilbert space is $N_{\text{level}} = 30$. The drive amplitudes $\Omega = 2\sqrt{\kappa}\alpha_{\text{in}}$ are chosen to coincide with the values used in the experiment, with $\alpha_{\text{in}} = \sqrt{P_{\text{in}}/(\hbar w_1)}$.

Figure 9 depicts the numerically calculated reflection coefficients S_{11} and the corresponding least-squares fits using Eq. (1). The colors are related to the drive power similarly to Fig. 2. The linear fit to the extracted Rabi frequencies shown in Fig. 9(d) confirms that the two-level approximation (qubit limit) is valid in the parameter space of our experiment.

We reproduce the experimental results presented in the main text in Fig. 3 by numerically calculating the reflection coefficient for the same range of probe frequency and power. Figure 10(a) depicts the phase of the reflection coefficient $\arg(S_{11})$ as a function of the incident power $P_{\rm in}$



FIG. 10. Numerical calculation of the energy spectrum. (a) Phase of the numerically calculated reflection coefficient $\arg(S_{11})$ as a function of probe frequency f and probe power P_{in} (left-hand panel) according to Appendix D. The multiphoton peaks are equally spaced in frequency, with the difference given by $K/2 = 2\pi \times 2.25$ MHz (right-hand panel). In contrast to the experiment, we observe a constant frequency shift K (orange markers, right-hand panel), as expected, because the Kerr Hamiltonian in Eq. (D1) only contains terms up to the fourth order. (b) Three individual traces (top panel) calculated at distinct drive powers ($P_{\text{probe}} = -121$, -106, and -101 dBm). Similarly to the experimental results shown in Fig. 3(b), several multiphoton transitions are visible at any given drive power in this range. With increasing power, the linewidth of the transitions broadens as depicted by the enlargements (bottom panels) around the third (right, $P_{\text{probe}} = -127$ to -123 dBm) and tenth (left, $P_{\text{probe}} = -105.75$ to -104.75 dBm) multiphoton transition.

and probe frequency *f*. Similar to the experiment, multiphoton transitions at frequencies $f_n = (E_n - E_0)/(nh)$ become visible. From a linear fit to the extracted multiphoton frequencies [see Fig. 10(a), right-hand panel], we recover the self-Kerr coefficient $K = 2\pi \times 4.5$ MHz set in the calculation, as expected. Since the Kerr Hamiltonian in Eq. (D1) does not contain beyond fourth-order terms, in contrast with the experimental results, the simulated K(n) is independent of the level number *n*. This confirms that the Hilbert-space dimension $N_{\text{level}} = 30$ was chosen sufficiently large.

For comparison to Fig. 3(b) shown in the main text, Fig. 10(b) shows the phase of the calculated reflection coefficient $\arg(S_{11})$ as a function of the probe frequency *f* for three drive powers, $P_{\rm in} = -121, -106$, and -101 dBm.

We would like to add that multiphoton transitions have been measured in flux qubits [66,67] and Cooper pair boxes [68,69], with the notable difference that in these previous cases the transitions are between the ground and the first excited state [70], while in our case they are between the ground and higher excited states.

APPENDIX E: TWO-TONE SPECTROSCOPY

Figure 11 shows a two-tone spectroscopy of the qubit sample in the vicinity of its fundamental transition frequency f_1 . We apply a fixed frequency drive tone at $\Delta_{\text{drive}} = 2\pi \times 200$ kHz above f_1 with varying drive power P_{drive} . Simultaneously, we measure the reflection coefficient S_{11} by applying a weak probe tone at varying frequency f and constant power $P_{\text{in}} = -160$ dBm.

For small drive powers, only a single response at the qubit frequency is visible in the phase of the reflection coefficient $\arg(S_{11})$ shown in Fig. 11(a). With increasing drive power, the occupation of the first excited state $|1\rangle$ increases and a second feature becomes visible 3.9 MHz below the qubit frequency, corresponding to the single-photon transition between the first and the second excited state $|1\rangle \rightarrow |2\rangle$, and quantifying the qubit anharmonicity α . The measured anharmonicity $\alpha = 2\pi \times 3.9$ MHz and the qubit frequency $f_1 = 7.6790$ GHz are slightly different compared to the values reported in the main text, due to the fact that the measurements were taken in different cooldowns and the sample parameters changed (most likely the grAl resistivity ρ_n). In total we performed seven cooldowns, summarized in Table II.

Both the $|0\rangle \rightarrow |1\rangle$ and $|1\rangle \rightarrow |2\rangle$ transitions split into two distinct transitions with increasing P_{drive} . This observation is in quantitative agreement with the theoretical modeling of a driven three-level system (qutrit) [35,71] [see Fig. 11(b)].

The expectation value of the photon number operator $\langle a^{\dagger}a \rangle$ is shown in Fig. 11(c), numerically calculated for a two-level (qubit, red) and a multilevel system (qudit, blue) with constant anharmonicity (cf. Appendix D). In contrast to a multilevel system, for a qubit the steady-state occupation number versus drive power saturates at 0.5. The red shaded area in Fig. 11(c) highlights the qubit limit in which



FIG. 11. Two-tone spectroscopy. (a) Phase of the reflection coefficient $arg(S_{11})$ measured with a weak probe tone of constant power $P_{\rm in} = -160$ dBm in the vicinity of the qubit frequency f_1 , while an additional microwave drive is applied at $\Delta_{\rm drive}/2\pi =$ $f_{\text{drive}} - f_1 = 200 \text{ kHz}$ detuning, indicated by the dashed white line. With increasing drive power P_{drive} , the fundamental transition starts to split into two distinct transitions, because of the Autler-Townes effect [71], observed at frequencies $f_{\pm} =$ $f_1 \pm \Omega_R/2\pi$ [35,71]. Since the population of the first excited state increases with drive power, at $P_{\text{drive}} \ge -150 \text{ dBm}$ a second transition becomes visible at 3.9 MHz below f_1 . This corresponds to the $|1\rangle \rightarrow |2\rangle$ transition. The measured anharmonicity $\alpha =$ $2\pi \times 3.9$ MHz, as well as the qubit frequency $f_1 = 7.6790$ GHz, are slightly different than the values reported in the main text, due to the fact that the measurements were taken in different cooldowns. In total we performed seven cooldowns, summarized in Table II. Similar to the fundamental transition, the second transition also splits with increasing P_{drive} [71]. (b) Extracted frequency splittings δf for the first two transitions. The black lines correspond to the theoretical predictions $2\Omega_R$ (first transition, purple markers) and Ω_R (second transition, yellow markers), respectively, with $\Omega_R = \sqrt{\Delta^2 + \Omega^2}$ and $\Omega =$ $\sqrt{4\kappa P_{\text{drive}}/hf_{\text{drive}}}$. (c) Expectation value for the photon number operator $\langle a^{\dagger}a \rangle$ as a function of the drive power P_{drive} numerically calculated for a qubit (red line) and for an anharmonic multilevel oscillator (see Appendix D).

the difference between the occupation numbers of an ideal qubit and our system (main text $\alpha = 2\pi \times 4.48$ MHz) is below 1%. The black arrow indicates the maximal drive power used for the resonance fluorescence measurements shown in Fig. 2.

APPENDIX F: MAGNETIC FIELD ALIGNMENT

Figure 12(a) shows the change in qubit frequency $\delta f_1 = f_1(B_z) - f_1$, as a function of B_z for $B_y = 0$. The field sweeps are the following: (i) $0 \rightarrow -0.2$ mT (blue),



FIG. 12. Qubit response to out-of-plane magnetic fields. (a) Change in qubit frequency $\delta f_1 = f_1(B_z) - f_1$ as a function of the out-of-plane compensation field B_z for $B_y = 0$. The colored arrows indicate the order of the measurement cycle. (b) Internal quality factor Q_i as a function of B_z extracted from the same measurement sequence. The internal quality factor exhibits a maximum around $B_z = -0.1$ mT, reaching a factor of 2 higher than the initial Q_i value in zero field [see Fig. 5(b), blue pentagons].

(ii) $-0.2 \rightarrow 0.2 \text{ mT}$ (green), (iii) $0.2 \rightarrow 0 \text{ mT}$ (purple), with the black arrow indicating the starting point. The qubit frequency decreases with increasing field magnitude and returns to its initial value when the field is swept in the opposite direction. For fields applied in positive *z* direction, we observe several jumps and a much less smooth change in the qubit frequency with field. This observation is not strictly related to the positive *z* direction, but depends on the order of the measurement sequence. Figure 12(b) shows the internal quality factor Q_i extracted from the same measurement sequence as the qubit frequency shown in Fig. 12(a).

The measurement shown in Fig. 12 emphasizes the circuit's pronounced susceptibility to out-of-plane magnetic fields. Interestingly, the maximum of the qubit frequency does not necessarily coincide with the maximal internal quality factor. The criterium for the in-plane field alignment is maximizing the qubit frequency versus B_z . By performing similar sweeps of B_z for different values of B_y , we estimate the misalignment between the HH field and the sample's in-plane direction to be 0.7°.

APPENDIX G: QUBIT RESPONSE TO IN-PLANE MAGNETIC FIELDS

The in-plane magnetic field dependence of the qubit transition frequency $f_1(B)$ is calculated by mapping the qubit onto a linearized, lumped-element circuit model consisting of three inductive contributions in series, which are shunted by a capacitance $C_s = 137$ fF. The inductive contributions arise from a field-independent geometric inductance $L_s = 0.45$ nH and two field-dependent kinetic inductances associated with the pure Al and grAl thin films,

 $L_{k,Al}(B)$ and $L_{k,grAl}(B)$, respectively. The lumped-element model transition frequency is

$$f_1 = \frac{1}{2\pi\sqrt{C_s(L_{k,\text{Al}}(B) + L_{k,\text{grAl}}(B) + L_s)}}.$$
 (G1)

The field dependence of the kinetic contributions is derived from Mattis-Bardeen theory for superconductors in the dirty limit [72] and assuming temperatures well below the critical temperature ($T \ll T_c$),

$$L_k = \frac{\hbar R_n}{\pi \Delta(B,T)},\tag{G2}$$

where R_n is the normal state resistance and $\Delta(B, T)$ is the magnetic field and temperature-dependent gap parameter. The dependence of the gap parameter on magnetic fields applied in plane is derived from a two-fluid model (see Ref. [44], pp. 392 and 393),

$$\Delta(B, T = 0) / \Delta_{00} = \sqrt{\frac{1 - (B/B_c)^2}{1 + (B/B_c)^2}},$$
 (G3)

where Δ_{00} is the gap parameter at zero temperature and zero magnetic field, and B_c is the critical magnetic flux density above which the pair correlation is zero. Because of the fact that the critical magnetic flux density of grAl [24,25] is 2 orders of magnitude higher than that of our pure Al films [17], we consider $L_{k,\text{grAl}}(B)$ to be constant. However, for the Al kinetic inductance, by inserting Eq. (G3) into Eq. (G2), we find

$$L_{k,\text{Al}}(B) = \frac{\hbar R_n}{\underbrace{\pi \Delta_{00,\text{Al}}}_{L_{k,\text{Al}}}} \sqrt{\frac{1 + (B/B_{c,\text{Al}})^2}{1 - (B/B_{c,\text{Al}})^2}}, \qquad (\text{G4})$$

where $L_{k,\text{Al}}$ is the kinetic inductance in zero field. Using Eq. (G1) we fit the data presented in Fig. 5(a) in the main text and we obtain $L_{k,\text{Al}} = 200 \pm 5$ pH and $B_{c,\text{Al}} = 150 \pm 5$ mT.

The 200 pH value of $L_{k,Al}$ corresponds to the intrinsic kinetic inductance of the Al film plus the contribution of the two contact areas between the grAl inductor and the Al electrodes. The presence of contact junctions is expected because the Al grains in grAl are uniformly covered by an amorphous AlO_x oxide. Taking into account the typically measured 15% kinetic inductance fraction in Al thin films of comparable geometry [58], we estimate the intrinsic kinetic contribution of the Al film to be 70 pH. The remaining 130 pH are associated with the contact junctions, from which we calculate a critical current $I_c \approx 5 \ \mu A$ for each of them, with corresponding critical current density $j_{c,JJ} \approx 0.13 \ mA/\mu m^2$, comparable to the critical current

density of the grAl film, $j_c = 0.4 \text{ mA}/\mu\text{m}^2$ [see Eq. (G7)]. The inductance participation of one contact junction in the total inductance is $p_{1,J} = 2\%$. Using the energy participation ratio method presented in Ref. [73], the nonlinear contribution of both junctions is

$$K_{1J} = \frac{h\omega_1^2}{4\Phi_0 I_c} p_{1J}^2 \approx 2\pi \times 5 \text{ kHz},$$
 (G5)

where $\Phi_0 = h/2e$ is the magnetic flux quantum.

We calculate the kinetic inductance of the grAl film $L_{k,\text{grAl}} = 2.65$ nH by subtracting $L_{k,\text{Al}} = 200$ pH [fitted, see Eq. (G4)] and $L_s = 450$ pH (finite element method simulations, cf. Appendix B) from the total inductance L = 3.3 nH, which we obtained from the measured resonance frequency $f_1 = 7.4887$ GHz (see Fig. 2) using $C_s = 137$ fF (finite element method simulations, see Appendix B). Considering the fact that the grAl volume consists of approximately 2.5 squares, the corresponding grAl sheet kinetic inductance is $L_{k,\Box} = 1.1$ nH/ \Box . This agrees with the value calculated from the room-temperature sheet resistance $R_{n,\Box} \approx 1800 \pm 200 \ \Omega/\Box$ using the Mattis-Bardeen theory for superconductors in the local and dirty limit [74]:

$$L_{K,\Box} = \frac{hR_{n,\Box}}{2\pi^2 \Delta_{\text{BCS}}} \approx 1.3 \pm 0.1 \text{ nH}/\Box.$$
(G6)

As discussed in the main text, the grAl nonlinearity α is consistent with a number $N \approx 6$ of effective JJs, yielding a critical current density,

$$j_c = \frac{\Phi_0}{2\pi} \frac{N}{L_{k,\text{grAl}} A_{\text{grAl}}} \approx 0.4 \text{ mA}/\mu\text{m}^2, \qquad (\text{G7})$$

where $A_{\text{grAl}} = 10 \times 200 \text{ nm}^2$ is the grAl cross-section area. This value for j_c is in agreement with switching current measurements of similar grAl films [75].

In Fig. 13 we show the field dependence of the nonlinear frequency shift K(5) and K(6) measured during the same two cooldowns as the data presented in Fig. 5 (main text), with and without an outer Al shield, respectively. We chose to measure the nonlinear coefficient for n > 1 in order to



FIG. 13. Measured nonlinear coefficients K(5) (shielded) and K(6) (unshielded) versus in-plane field.

use a larger read-out power and reduce the averaging time during the field sweep. As expected, since the ratio ω_1^2/j_c in the expression for *K* remains constant, we do not observe a change in *K* within the measurement accuracy.

APPENDIX H: INTERACTIONS WITH OTHER MESOSCOPIC SYSTEMS

Unwanted interactions between superconducting qubits and other mesoscopic systems are commonly observed [76–79]. Although the nature of the mesoscopic system is difficult to identify, and depends on the architecture of the qubit in general, among the most prominent suspects are defects present in the nonstoichiometric oxide of the JJ barrier and other interfaces [79,80], adsorbates and organic residuals from the fabrication process [81], nonequilibrium quasiparticles [82–85], and magnetic vortices [86]. The interaction can be either transversal, causing a change of the underlying eigenbase due to a hybridization between the two systems, or longitudinal, inducing a frequency shift of the qubit that depends on the state of the mesoscopic system. For a true longitudinal coupling, the state-dependent frequency shift does not depend on the frequency detuning between the systems. In the transversal case, the hybridization becomes visible in the form of an avoided level crossing, when the two systems are tuned on resonance [87].

We can tune the grAl transmon qubit transition frequency by more than 150 MHz by applying an external magnetic field in plane. Figure 14(a) shows the qubit



FIG. 14. Interactions with other mesoscopic systems. (a) Qubit transition frequency f_1 as a function of the applied in-plane magnetic field B_y measured in two different cooldowns. The black dashed lines indicate fits to Eq. (G1). (b) Frequency difference Δf_1 between the measured transition frequency $f_{1,\text{meas}}$ and the fit result $f_{1,\text{fit}}$ [see Eq. (G1)] in three different field ranges. On this scale, discrete jumps in the qubit frequency become visible for the data taken in run no. 5. The jumps remain qualitatively unchanged over a 150 MHz span covered by the qubit frequency versus B_y , and in neither of the runs did we observe signatures of avoided level crossings.

	Run no. 1	Run no. 2	Run no. 3	Run no. 4	Run no. 5	Run no. 6	Run no. 7
f_1 (GHz)	7.6790	7.4887	7.5156	7.4778	7.672	7.7292	7.4749
$\alpha/2\pi$ (MHz)	3.90	4.48				3.35	4.5
$Q_{c,0}(\times 10^5)$	1.7	1.9	1.8	1.5	1.9	1.9	1.5
$Q_{i,0}(\times 10^3)$	900	750	95	100	130	51	750
$\kappa_0/2\pi$ (kHz)	45	40	42	50	40	40	51
$\gamma_0/2\pi$ (kHz)	8.5	10	78	75	58	150	10
Outer shield:							
Cu	Yes						
Al	Yes	Yes	No	Yes	No	No	Yes
μ metal	Yes	Yes	No	No	No	No	Yes
Magnetic field	No	No	Yes	Yes	Yes	Yes	No

TABLE II. Summary of circuit parameters from all measurement runs: qubit frequency f_1 , external quality factor (zero field) $Q_{c,0}$, internal quality factor (zero field) $Q_{i,0}$, external coupling rate (zero field) κ_0 , internal decay rate (zero field) γ_0 , outer shielding configuration.

transition frequency as a function of the in-plane magnetic field B_y measured in two consecutive cooldowns (run no. 5 and run no. 6), as well as numerical fits according to Eq. (G1) (black dashed lines). Each frequency value is extracted from a fit to the resonance fluorescence response of the qubit similar to Fig. 2. In both measurements shown, and in any other measurement of the same kind, we do not observe avoided level crossings. Figure 14(b) depicts the frequency difference Δf_1 between the measured transition frequency $f_{1,\text{meas}}$ and the fitted transition frequency $f_{1,\text{fit}}$ in three different field ranges. In run no. 5, the qubit frequency is observed to jump between two metastable states, while it



FIG. 15. Film height profile. Atomic force microscope image of the film height *z* in the area around the grAl inductor, measured on a sample fabricated on the same wafer as the sample presented in the main text. The inset shows the cross section along *x* (black) and *y* (gray), as indicated by the arrows and overlay lines in the 3D plot. The cross section along the grAl inductor (gray) confirms the $t_{grAl} = 10$ nm grAl thickness and $t_{Al} = 40$ nm for each Al layer.

shows no significant discontinuity in run no. 6. The fact that the observed frequency difference between the two metastable states during run no. 5 is independent of the transition frequency of the qubit suggests that the coupling is longitudinal.

APPENDIX I: SUMMARY OF CIRCUIT PARAMETERS IN ALL COOLDOWNS

In Table II we summarize the circuit parameters measured in each of the seven cooldowns. The time intervals between subsequent runs, during which the sample is at room temperature and atmospheric pressure, therefore subjected to aging, are the following: run 1–2, 20 days; run 2–3, 50 days; run 3–4, 20 days; run 4–5, 176 days; run 5–6, 3 days; run 6–7, 102 days.

APPENDIX J: FILM HEIGHT PROFILE

Figure 15 shows an atomic force microscopy (AFM) image of the film height around the grAl volume for a sample fabricated in the same batch. The height profile shows several steps which originate from the three-angle evaporation process with angles 0° (grAl, $t_{grAl} = 10$ nm) and $\pm 35^{\circ}$ (Al, $t_{Al} = 40$ nm each). The metal deposition parameters are summarized in Table III. The main features are the leads connecting the grAl volume. Close to the edge of the image, all three layers overlap and the total film height is around 90 nm. The inset in Fig. 15 shows a cross

TABLE III. Metal deposition parameters: film thickness t, evaporation angle β , deposition rate r, absolute pressure in deposition chamber p.

Layer	t (nm)	$\beta(^{\circ})$	<i>r</i> (nm/s)	p (mbar)
grAl	10	0	0.3	$\sim 10^{-5}$
Al	40	+35	1.0	$\sim 6 \times 10^{-8}$
Al	40	-35	1.0	$\sim 6 \times 10^{-8}$

- P. Krantz, M. Kjaergaard, F. Yan, T. P. Orlando, S. Gustavsson, and W. D. Oliver, A Quantum Engineer's Guide to Superconducting Qubits, Appl. Phys. Rev. 6, 021318 (2019).
- [2] N. Samkharadze, G. Zheng, N. Kalhor, D. Brousse, A. Sammak, U. C. Mendes, A. Blais, G. Scappucci, and L. M. K. Vandersypen, *Strong Spin-Photon Coupling in Silicon*, Science **359**, 1123 (2018).
- [3] A. J. Landig, J. V. Koski, P. Scarlino, U. C. Mendes, A. Blais, C. Reichl, W. Wegscheider, A. Wallraff, K. Ensslin, and T. Ihn, *Coherent Spin-Photon Coupling Using a Resonant Exchange Qubit*, Nature (London) 560, 179 (2018).
- [4] X. Mi, M. Benito, S. Putz, D. M. Zajac, J. M. Taylor, G. Burkard, and J. R. Petta, A Coherent Spin-Photon Interface in Silicon, Nature (London) 555, 599 (2018).
- [5] J. G. Kroll, W. Uilhoorn, K. L. van der Enden, D. de Jong, K. Watanabe, T. Taniguchi, S. Goswami, M. C. Cassidy, and L. P. Kouwenhoven, *Magnetic Field Compatible Circuit Quantum Electrodynamics with Graphene Josephson Junctions*, Nat. Commun. 9, 4615 (2018).
- [6] A. Fornieri, A. M. Whiticar, F. Setiawan, E. Portolés, A. C. C. Drachmann, A. Keselman, S. Gronin, C. Thomas, T. Wang, R. Kallaher, G. C. Gardner, E. Berg, M. J. Manfra, A. Stern, C. M. Marcus, and F. Nichele, *Evidence of Topological Superconductivity in Planar Josephson Junctions*, Nature (London) **569**, 89 (2019).
- [7] M. Pita-Vidal, A. Bargerbos, C.-K. Yang, D. J. van Woerkom, W. Pfaff, N. Haider, P. Krogstrup, L. P. Kouwenhoven, G. de Lange, and A. Kou, *A Gate-Tunable, Field-Compatible Fluxonium*, arXiv:1910.07978.
- [8] Y. Tabuchi, S. Ishino, T. Ishikawa, R. Yamazaki, K. Usami, and Y. Nakamura, *Hybridizing Ferromagnetic Magnons* and Microwave Photons in the Quantum Limit, Phys. Rev. Lett. **113**, 083603 (2014).
- [9] L. Bogani and W. Wernsdorfer, *Molecular Spintronics* Using Single-Molecule Magnets, Nat. Mater. 7, 179 (2008).
- [10] A. Bienfait, J. J. Pla, Y. Kubo, M. Stern, X. Zhou, C. C. Lo, C. D. Weis, T. Schenkel, M. L. W. Thewalt, D. Vion, D. Esteve, B. Julsgaard, K. Mølmer, J. J. L. Morton, and P. Bertet, *Reaching the Quantum Limit of Sensitivity in Electron Spin Resonance*, Nat. Nanotechnol. **11**, 253 (2016).
- [11] A. Bienfait, J. J. Pla, Y. Kubo, X. Zhou, M. Stern, C. C. Lo, C. D. Weis, T. Schenkel, D. Vion, D. Esteve, J. J. L. Morton, and P. Bertet, *Controlling Spin Relaxation with a Cavity*, Nature (London) 531, 74 (2016).
- [12] C. Godfrin, A. Ferhat, R. Ballou, S. Klyatskaya, M. Ruben, W. Wernsdorfer, and F. Balestro, *Operating Quantum States in Single Magnetic Molecules: Implementation of Grover's Quantum Algorithm*, Phys. Rev. Lett. **119**, 187702 (2017).
- [13] A. Blais, R.-S. Huang, A. Wallraff, S. M. Girvin, and R. J. Schoelkopf, *Cavity Quantum Electrodynamics for Superconducting Electrical Circuits: An Architecture for Quantum Computation*, Phys. Rev. A 69, 062320 (2004).

- [14] H. Paik, D. I. Schuster, L. S. Bishop, G. Kirchmair, G. Catelani, A. P. Sears, B. R. Johnson, M. J. Reagor, L. Frunzio, L. I. Glazman, S. M. Girvin, M. H. Devoret, and R. J. Schoelkopf, *Observation of High Coherence in Josephson Junction Qubits Measured in a Three-Dimensional Circuit QED Architecture*, Phys. Rev. Lett. **107**, 240501 (2011).
- [15] Y. Kubo, C. Grezes, A. Dewes, T. Umeda, J. Isoya, H. Sumiya, N. Morishita, H. Abe, S. Onoda, T. Ohshima, V. Jacques, A. Dréau, J.-F. Roch, I. Diniz, A. Auffeves, D. Vion, D. Esteve, and P. Bertet, *Hybrid Quantum Circuit with a Superconducting Qubit Coupled to a Spin Ensemble*, Phys. Rev. Lett. **107**, 220501 (2011).
- [16] V. Ranjan, G. de Lange, R. Schutjens, T. Debelhoir, J. P. Groen, D. Szombati, D. J. Thoen, T. M. Klapwijk, R. Hanson, and L. DiCarlo, *Probing Dynamics of an Electron-Spin Ensemble via a Superconducting Resonator*, Phys. Rev. Lett. **110**, 067004 (2013).
- [17] R. Meservey and P.M. Tedrow, *Properties of Very Thin Aluminum Films*, J. Appl. Phys. **42**, 51 (1971).
- [18] A. Schneider, T. Wolz, M. Pfirrmann, M. Spiecker, H. Rotzinger, A. V. Ustinov, and M. Weides, *Transmon Qubit in a Magnetic Field: Evolution of Coherence and Transition Frequency*, Phys. Rev. Research 1, 023003 (2019).
- [19] U. S. Pracht, N. Bachar, L. Benfatto, G. Deutscher, E. Farber, M. Dressel, and M. Scheffler, *Enhanced Cooper Pairing versus Suppressed Phase Coherence Shaping the Superconducting Dome in Coupled Aluminum Nanograins*, Phys. Rev. B **93**, 100503(R) (2016).
- [20] J. Koch, T. M. Yu, J. Gambetta, A. A. Houck, D. I. Schuster, J. Majer, A. Blais, M. H. Devoret, S. M. Girvin, and R. J. Schoelkopf, *Charge-Insensitive Qubit Design Derived from the Cooper Pair Box*, Phys. Rev. A **76**, 042319 (2007).
- [21] D. Niepce, J. Burnett, and J. Bylander, *High Kinetic Inductance NbN Nanowire Superinductors*, Phys. Rev. Applied **11**, 044014 (2019).
- [22] N. Samkharadze, A. Bruno, P. Scarlino, G. Zheng, D. P. DiVincenzo, L. DiCarlo, and L. M. K. Vandersypen, *High-Kinetic-Inductance Superconducting Nanowire Resonators* for Circuit QED in a Magnetic Field, Phys. Rev. Applied 5, 044004 (2016).
- [23] A. Shearrow, G. Koolstra, S. J. Whiteley, N. Earnest, P. S. Barry, F. J. Heremans, D. D. Awschalom, E. Shirokoff, and D. I. Schuster, *Atomic Layer Deposition of Titanium Nitride for Quantum Circuits*, Appl. Phys. Lett. **113**, 212601 (2018).
- [24] R. W. Cohen and B. Abeles, Superconductivity in Granular Aluminum Films, Phys. Rev. 168, 444 (1968).
- [25] K. Borisov, D. Rieger, P. Winkel, F. Henriques, F. Valenti, A. Ionita, M. Wessbecher, M. Spiecker, D. Gusenkova, I. M. Pop, and W. Wernsdorfer, *Superconducting Granular Aluminum Resonators Resilient to Magnetic Fields up to 1 Tesla*, arXiv:2006.05171.
- [26] L. Grünhaupt, N. Maleeva, S. T. Skacel, M. Calvo, F. Levy-Bertrand, A. V. Ustinov, H. Rotzinger, A. Monfardini, G. Catelani, and I. M. Pop, *Loss Mechanisms and Quasiparticle Dynamics in Superconducting Microwave Resonators Made of Thin-Film Granular Aluminum*, Phys. Rev. Lett. **121**, 117001 (2018).
- [27] W. Zhang, K. Kalashnikov, W.-S. Lu, P. Kamenov, T. DiNapoli, and M.E. Gershenson, *Microresonators*

Fabricated from High-Kinetic-Inductance Aluminum films, Phys. Rev. Applied **11**, 011003 (2019).

- [28] L. Grünhaupt, M. Spiecker, D. Gusenkova, N. Maleeva, S. T. Skacel, I. Takmakov, F. Valenti, P. Winkel, H. Rotzinger, W. Wernsdorfer, A. V. Ustinov, and I. M. Pop, *Granular Aluminum as a Superconducting Material for High-Impedance Quantum Circuits*, Nat. Mater. 18, 816 (2019).
- [29] P. Kamenov, W.-S. Lu, K. Kalashnikov, T. DiNapoli, M. T. Bell, and M. E. Gershenson, *Granular Aluminum Meandered Superinductors for Quantum Circuits*, Phys. Rev. Applied 13, 054051 (2020).
- [30] N. Maleeva, L. Grünhaupt, T. Klein, F. Levy-Bertrand, O. Dupre, M. Calvo, F. Valenti, P. Winkel, F. Friedrich, W. Wernsdorfer, A. V. Ustinov, H. Rotzinger, A. Monfardini, M. V. Fistul, and I. M. Pop, *Circuit Quantum Electrodynamics of Granular Aluminum Resonators*, Nat. Commun. 9, 3889 (2018).
- [31] Y. Schön, J. N. Voss, M. Wildermuth, A. Schneider, S. T. Skacel, M. P. Weides, J. H. Cole, H. Rotzinger, and A. V. Ustinov, *Rabi Oscillations in a Superconducting Nanowire Circuit*, npj Quantum Mater. 5, 18 (2020).
- [32] G. Deutscher, H. Fenichel, M. Gershenson, E. Grünbaum, and Z. Ovadyahu, *Transition to Zero Dimensionality in Granular Aluminum Superconducting Films*, J. Low Temp. Phys. **10**, 231 (1973).
- [33] F. Valenti, F. Henriques, G. Catelani, N. Maleeva, L. Grünhaupt, U. von Lüpke, S. T. Skacel, P. Winkel, A. Bilmes, A. V. Ustinov, J. Goupy, M. Calvo, A. Benoît, F. Levy-Bertrand, A. Monfardini, and I. M. Pop, *Interplay between Kinetic Inductance, Nonlinearity, and Quasiparticle Dynamics in Granular Aluminum Microwave Kinetic Inductance Detectors*, Phys. Rev. Applied **11**, 054087 (2019).
- [34] A. Kou, W. C. Smith, U. Vool, I. M. Pop, K. M. Sliwa, M. Hatridge, L. Frunzio, and M. H. Devoret, *Simultaneous Monitoring of Fluxonium Qubits in a Waveguide*, Phys. Rev. Applied 9, 064022 (2018).
- [35] O. Astafiev, A. M. Zagoskin, A. A. Abdumalikov, Y. A. Pashkin, T. Yamamoto, K. Inomata, Y. Nakamura, and J. S. Tsai, *Resonance Fluorescence of a Single Artificial Atom*, Science **327**, 840 (2010).
- [36] E. M. Purcell, H. C. Torrey, and R. V. Pound, *Resonance Absorption by Nuclear Magnetic Moments in a Solid*, Phys. Rev. 69, 37 (1946).
- [37] D. I. Schuster, *Circuit Quantum Electrodynamics*, Ph.D. Thesis, Yale University, 2007.
- [38] J. Braumüller, J. Cramer, S. Schlör, H. Rotzinger, L. Radtke, A. Lukashenko, P. Yang, S. T. Skacel, S. Probst, M. Marthaler, L. Guo, A. V. Ustinov, and M. Weides, *Multiphoton Dressing of an Anharmonic Superconducting Many-Level Quantum Circuit*, Phys. Rev. B **91**, 054523 (2015).
- [39] C. Eichler and A. Wallraff, *Controlling the Dynamic Range of a Josephson Parametric Amplifier*, Eur. Phys. J. Quantum Technol. 1, 2 (2014).
- [40] V. V. Sivak, N. E. Frattini, V. R. Joshi, A. Lingenfelter, S. Shankar, and M. H. Devoret, *Kerr-Free Three-Wave Mixing in Superconducting Quantum Circuits*, Phys. Rev. Applied 11, 054060 (2019).
- [41] F. Yang, T. Storbeck, T. Gozlinski, L. Grünhaupt, I. M. Pop, and W. Wulfhekel, *Microscopic Charging and In-Gap*

States in Superconducting Granular Aluminum, arXiv: 1911.02312.

- [42] A. A. Abdumalikov, O. V. Astafiev, Y. A. Pashkin, Y. Nakamura, and J. S. Tsai, *Dynamics of Coherent and Incoherent Emission from an Artificial Atom in a 1D Space*, Phys. Rev. Lett. **107**, 043604 (2011).
- [43] P. Winkel, I. Takmakov, D. Rieger, L. Planat, W. Hasch-Guichard, L. Grünhaupt, N. Maleeva, F. Foroughi, F. Henriques, K. Borisov, J. Ferrero, A. V. Ustinov, W. Wernsdorfer, N. Roch, and I. M. Pop, *Nondegenerate Parametric Amplifiers Based on Dispersion-Engineered Josephson-Junction Arrays*, Phys. Rev. Applied 13, 024015 (2020).
- [44] M. Tinkham, Introduction to Superconductivity, 2nd. ed. (Dover Publications, Inc., Mineola, New York, 2004).
- [45] R. Lescanne, L. Verney, Q. Ficheux, M. H. Devoret, B. Huard, M. Mirrahimi, and Z. Leghtas, *Escape of a Driven Quantum Josephson Circuit into Unconfined States*, Phys. Rev. Applied **11**, 014030 (2019).
- [46] S. Puri, S. Boutin, and A. Blais, Engineering the Quantum States of Light in a Kerr-Nonlinear Resonator by Two-Photon Driving, npj Quantum Inf. 3, 18 (2017).
- [47] Y. Y. Gao, B. J. Lester, K. S. Chou, L. Frunzio, M. H. Devoret, L. Jiang, S. M. Girvin, and R. J. Schoelkopf, *Entanglement of Bosonic Modes through an Engineered Exchange Interaction*, Nature (London) 566, 509 (2019).
- [48] P. Campagne-Ibarcq, A. Eickbusch, S. Touzard, E. Zalys-Geller, N. E. Frattini, V. V. Sivak, P. Reinhold, S. Puri, S. Shankar, R. J. Schoelkopf, L. Frunzio, M. Mirrahimi, and M. H. Devoret, *Quantum Error Correction of a Qubit Encoded in Grid States of an Oscillator*, arXiv:1907.12487.
- [49] S. Kwon, A. F. Roudsari, O. W. B. Benningshof, Y.-C. Tang, H. R. Mohebbi, I. A. J. Taminiau, D. Langenberg, S. Lee, G. Nichols, D. G. Cory, and G.-X. Miao, *Magnetic Field Dependent Microwave Losses in Superconducting Niobium Microstrip Resonators*, J. Appl. Phys. **124**, 033903 (2018).
- [50] R.-P. Riwar and G. Catelani, *Efficient Quasiparticle Traps with Low Dissipation through Gap Engineering*, Phys. Rev. B 100, 144514 (2019).
- [51] F. Henriques, F. Valenti, T. Charpentier, M. Lagoin, C. Gouriou, M. Martínez, L. Cardani, M. Vignati, L. Grünhaupt, D. Gusenkova, J. Ferrero, S. T. Skacel, W. Wernsdorfer, A. V. Ustinov, G. Catelani, O. Sander, and I. M. Pop, *Phonon Traps Reduce the Quasiparticle Density in Superconducting Circuits*, Appl. Phys. Lett. **115**, 212601 (2019).
- [52] K. Karatsu, A. Endo, J. Bueno, P. J. de Visser, R. Barends, D. J. Thoen, V. Murugesan, N. Tomita, and J. J. A. Baselmans, *Mitigation of Cosmic Ray Effect on Microwave Kinetic Inductance Detector Arrays*, Appl. Phys. Lett. **114**, 032601 (2019).
- [53] R. Dassonneville, T. Ramos, V. Milchakov, L. Planat, E. Dumur, F. Foroughi, J. Puertas, S. Leger, K. Bharadwaj, J. Delaforce, C. Naud, W. Hasch-Guichard, J. J. García-Ripoll, N. Roch, and O. Buisson, *Fast High-Fidelity Quantum Nondemolition Qubit Readout via a Nonperturbative Cross-Kerr Coupling*, Phys. Rev. X 10, 011045 (2020).
- [54] F. Motzoi, J. M. Gambetta, P. Rebentrost, and F. K. Wilhelm, Simple Pulses for Elimination of Leakage in Weakly Nonlinear Qubits, Phys. Rev. Lett. 103, 110501 (2009).

- [55] V.E. Manucharyan, J. Koch, L.I. Glazman, and M.H. Devoret, *Fluxonium: Single Cooper-Pair Circuit Free of Charge Offsets*, Science **326**, 113 (2009).
- [56] qKit—a quantum measurement suite in PYTHON, https:// github.com/qkitgroup/qkit.
- [57] G. Donnier-Valentin and W. Wernsdorfer, *Table-Top Dilution Cryostat: Sionludi*, Néel Highlights 4 (2012), http:// www.neel.cnrs.fr/IMG/pdf/Table-top_dilution.pdf.
- [58] L. Grünhaupt, U. von Lüpke, D. Gusenkova, S. T. Skacel, N. Maleeva, S. Schlör, A. Bilmes, H. Rotzinger, A. V. Ustinov, M. Weides, and I. M. Pop, An Argon Ion Beam Milling Process for Native AlO_x Layers Enabling Coherent Superconducting Contacts, Appl. Phys. Lett. **111**, 072601 (2017).
- [59] E. Caparelli and D. Tomasi, An Analytical Calculation of the Magnetic Field Using the Biot Savart Law, Rev. Bras. Ensino Fis. 23, 284 (2001).
- [60] S. Richer, N. Maleeva, S. T. Skacel, I. M. Pop, and D. DiVincenzo, *Inductively Shunted Transmon Qubit with Tunable Transverse and Longitudinal Coupling*, Phys. Rev. B 96, 174520 (2017).
- [61] N. Cottet, Energy and Information in Fluorescence with Superconducting Circuits, Ph.D. thesis, PSL Research University, Ecole Normale Superieure, 2018.
- [62] C. W. Gardiner and M. J. Collett, Input and Output in Damped Quantum Systems: Quantum Stochastic Differential Equations and the Master Equation, Phys. Rev. A 31, 3761 (1985).
- [63] A. A. Clerk, M. H. Devoret, S. M. Girvin, F. Marquardt, and R. J. Schoelkopf, *Introduction to Quantum Noise, Measurement, and Amplification*, Rev. Mod. Phys. 82, 1155 (2010).
- [64] J. Johansson, P. Nation, and F. Nori, *QuTiP: An Open-Source PYTHON Framework for the Dynamics of Open Quantum Systems*, Comput. Phys. Commun. **183**, 1760 (2012).
- [65] J. Johansson, P. Nation, and F. Nori, *QuTIP 2: A PYTHON Framework for the Dynamics of Open Quantum Systems*, Comput. Phys. Commun. **184**, 1234 (2013).
- [66] W. D. Oliver, Y. Yu, J. C. Lee, K. K. Berggren, L. S. Levitov, and T. P. Orlando, *Mach-Zehnder Interferometry in a Strongly Driven Superconducting Qubit*, Science **310**, 1653 (2005).
- [67] A. Izmalkov, S. H. W. van der Ploeg, S. N. Shevchenko, M. Grajcar, E. Il'ichev, U. Hübner, A. N. Omelyanchouk, and H.-G. Meyer, *Consistency of Ground State and Spectroscopic Measurements on Flux Qubits*, Phys. Rev. Lett. 101, 017003 (2008).
- [68] C. M. Wilson, T. Duty, F. Persson, M. Sandberg, G. Johansson, and P. Delsing, *Coherence Times of Dressed States of a Superconducting Qubit Under Extreme Driving*, Phys. Rev. Lett. **98**, 257003 (2007).
- [69] M. Sillanpää, T. Lehtinen, A. Paila, Y. Makhlin, and P. Hakonen, *Continuous-Time Monitoring of Landau-Zener Interference in a Cooper-Pair Box*, Phys. Rev. Lett. 96, 187002 (2006).
- [70] S. Shevchenko, S. Ashhab, and F. Nori, *Landau-Zener-Stückelberg Interferometry*, Phys. Rep. **492**, 1 (2010).
- [71] M. Baur, S. Filipp, R. Bianchetti, J. M. Fink, M. Göppl, L. Steffen, P. J. Leek, A. Blais, and A. Wallraff, *Measurement of Autler-Townes and Mollow Transitions in a Strongly Driven Superconducting Qubit*, Phys. Rev. Lett. **102**, 243602 (2009).
- [72] D. C. Mattis and J. Bardeen, *Theory of the Anomalous Skin* Effect in Normal and Superconducting Metals, Phys. Rev. 111, 412 (1958).

- [73] Z. K. Minev, S. O. Mundhada, S. Shankar, P. Reinhold, R. Gutiérrez-Jáuregui, R. J. Schoelkopf, M. Mirrahimi, H. J. Carmichael, and M. H. Devoret, *To Catch and Reverse a Quantum Jump Mid-Flight*, Nature (London) **570**, 200 (2019).
- [74] D. C. Mattis and J. Bardeen, *Theory of the Anomalous Skin Effect in Normal and Superconducting Metals*, Phys. Rev. 111, 412 (1958).
- [75] F. Friedrich, P. Winkel, K. Borisov, H. Seeger, C. Sürgers, I. M. Pop, and W. Wernsdorfer, Onset of Phase Diffusion in High Kinetic Inductance Granular Aluminum Micro-SQUIDs, Supercond. Sci. Technol. 32, 125008 (2019).
- [76] P. V. Klimov et al., Fluctuations of Energy-Relaxation Times in Superconducting Qubits, Phys. Rev. Lett. 121, 090502 (2018).
- [77] H. le Sueur, A. Svilans, N. Bourlet, A. Murani, L. Berge, L. Dumoulin, and P. Joyez, *Microscopic Charged Fluctuators* as a Limit to the Coherence of Disordered Superconductor Devices, arXiv:1810.12801.
- [78] S. Schlör, J. Lisenfeld, C. Müller, A. Bilmes, A. Schneider, D. P. Pappas, A. V. Ustinov, and M. Weides, *Correlating Decoherence in Transmon Qubits: Low Frequency Noise by Single Fluctuators*, Phys. Rev. Lett. **123**, 190502 (2019).
- [79] J. Lisenfeld, A. Bilmes, A. Megrant, R. Barends, J. Kelly, P. Klimov, G. Weiss, J. M. Martinis, and A. V. Ustinov, *Electric Field Spectroscopy of Material Defects in Transmon Qubits*, npj Quantum Inf. 5, 105 (2019).
- [80] C. Müller, J. H. Cole, and J. Lisenfeld, *Towards Under-standing Two-Level-Systems in Amorphous Solids: Insights from Quantum Circuits*, Rep. Prog. Phys. 82, 124501 (2019).
- [81] S. E. de Graaf, L. Faoro, J. Burnett, A. A. Adamyan, A. Y. Tzalenchuk, S. E. Kubatkin, T. Lindström, and A. V. Danilov, *Suppression of Low-Frequency Charge Noise in Superconducting Resonators by Surface Spin Desorption*, Nat. Commun. 9, 1143 (2018).
- [82] P. J. de Visser, J. J. A. Baselmans, P. Diener, S. J. C. Yates, A. Endo, and T. M. Klapwijk, *Number Fluctuations of Sparse Quasiparticles in a Superconductor*, Phys. Rev. Lett. **106**, 167004 (2011).
- [83] D. Ristè, C. C. Bultink, M. J. Tiggelman, R. N. Schouten, K. W. Lehnert, and L. DiCarlo, *Millisecond Charge-Parity Fluctuations and Induced Decoherence in a Superconducting Transmon Qubit*, Nat. Commun. 4, 1913 (2013).
- [84] I. M. Pop, K. Geerlings, G. Catelani, R. J. Schoelkopf, L. I. Glazman, and M. H. Devoret, *Coherent Suppression of Electromagnetic Dissipation due to Superconducting Quasiparticles*, Nature (London) **508**, 369 (2014).
- [85] C. Wang, Y. Y. Gao, I. M. Pop, U. Vool, C. Axline, T. Brecht, R. W. Heeres, L. Frunzio, M. H. Devoret, G. Catelani, L. I. Glazman, and R. J. Schoelkopf, *Measurement and Control of Quasiparticle Dynamics in a Superconducting Qubit*, Nat. Commun. 5, 5836 (2014).
- [86] C. Song, T. W. Heitmann, M. P. DeFeo, K. Yu, R. McDermott, M. Neeley, J. M. Martinis, and B. L. T. Plourde, *Microwave Response of Vortices in Superconducting Thin Films of Re and Al*, Phys. Rev. B **79**, 174512 (2009).
- [87] J. M. Martinis, K. B. Cooper, R. McDermott, M. Steffen, M. Ansmann, K. D. Osborn, K. Cicak, S. Oh, D. P. Pappas, R. W. Simmonds, and C. C. Yu, *Decoherence in Josephson Qubits from Dielectric Loss*, Phys. Rev. Lett. **95**, 210503 (2005).